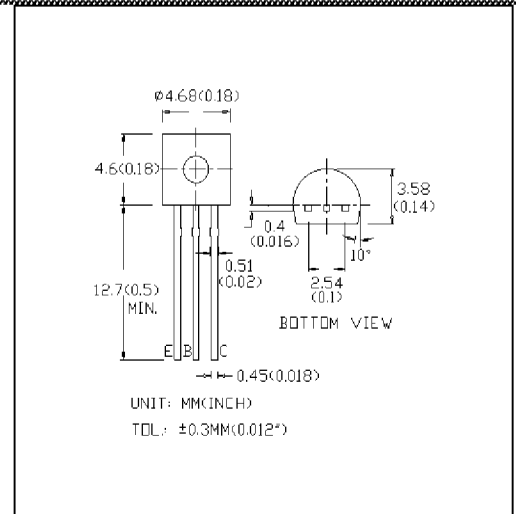


### DESCRIPTION

BC450 is PNP silicon planar transistor designed for use as high voltage driver and output transistor. Particularly suitable as power darlington drivers.



### ABSOLUTE MAXIMUM RATINGS

Collector-Emitter Voltage	V <sub>CEO</sub>	100V
Collector-Base Voltage	V <sub>CB0</sub>	100V
Emitter-Base Voltage	V <sub>EB0</sub>	5V
Collector Current Continuous	I <sub>C</sub>	300mA
Total Power Dissipation @ Ta < 25°C	P <sub>tot</sub>	625mW
Operating & Storage Junction Temperature	T <sub>j</sub> , T <sub>stg</sub>	-55 to +150°C

### ELECTRO-OPTICAL CHARACTERISTICS (Ta = 25°C)

PARAMETER	SYMBOL	MIN	MAX	UNIT	CONDITIONS
Collector-Emitter Breakdown Voltage	LV <sub>CEO</sub> *	100		V	I <sub>C</sub> = 1mA, I <sub>B</sub> = 0
Collector-Base Breakdown Voltage	BV <sub>CB0</sub>	100		V	I <sub>C</sub> = 0.1mA, I <sub>E</sub> = 0
Emitter-Base Breakdown Voltage	BV <sub>EB0</sub>	4		V	I <sub>E</sub> = 0.01mA, I <sub>C</sub> = 0
Collector Cutoff Current	I <sub>CB0</sub>		100	nA	V <sub>CB</sub> = 60V, I <sub>E</sub> = 0
D.C. Current Gain	HFE*	50	460		I <sub>C</sub> = 2mA**, V <sub>CE</sub> = 5V
		50			I <sub>C</sub> = 10mA**, V <sub>CE</sub> = 5V
		50			I <sub>C</sub> = 100mA**, V <sub>CE</sub> = 5V
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub> *		0.25	V	I <sub>C</sub> = 100mA, I <sub>B</sub> = 10mA
Base-Emitter Saturation Voltage	V <sub>BE(sat)</sub> *	0.85	TYP.	V	I <sub>C</sub> = 100mA, I <sub>B</sub> = 10mA
Base-Emitter Voltage	V <sub>BE</sub> *		1.2	V	I <sub>C</sub> = 100mA, V <sub>CE</sub> = 5V
Current Gain Bandwidth Product	f <sub>T</sub>	100		MHz	I <sub>C</sub> = 50mA, V <sub>CE</sub> = 5V f = 100MHz
Output Capacitance	C <sub>ob</sub>	3	TYP.	pF	V <sub>CB</sub> = 10V, f = 1MHz
Input Capacitance	C <sub>ib</sub>	20	TYP.	pF	V <sub>EB</sub> = 0.5V, f = 1MHz

\* Pulse test : pulse width < 300μs, duty cycle < 1%.

HFE GROUPING :	Full range	Group A	Group B
@ I <sub>C</sub> = 2mA V <sub>CE</sub> = 5V	50-460	120-220	180-460
@ I <sub>C</sub> = 10mA V <sub>CE</sub> = 5V	50 min	100 min	160 min
@ I <sub>C</sub> = 100mA V <sub>CE</sub> = 5V	50 min	60 min	90 min